DESCRIPTION
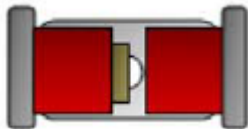
The LLDB3 is available in LL-34 package

ORDERING INFORMATION

Package Type	Part Number
LL-34	LLDB3
Note	SPQ: 2,500pcs/Reel
AiT provides all RoHS Compliant Products	

PIN DESCRIPTION

Small Signal Diode

FEATURES

● Surface device type mounting.

● Hermetically Sealed Glass.

● Matte Tin (Sn) Terminal Finish

● All external surfaces are corrosion resistant and terminals are readily solderable.

● Available in LL-34 package

MECHANICAL DATA

Case: MINI-MELF Package

Terminal: Pure tin plated, lead free. solderable per MIL-STD-202, Method 208 guaranteed

High temperature soldering guaranteed: 260°C /10s

Weight :29 ± 2.5 mg

ABSOLUTE MAXIMUM RATINGS

Rating at 25.C ambient temperature unless otherwise specified

P_D, Power Dissipation		150mW
I_{FRM}, Repetitive Peak Forward Current	Pulse Width=20µsec	2A
$R_{\theta JA}$, Thermal Resistance (Junction to Ambient)NOTE 1		400°C/W
T_J, T_{STG}, Junction and Storage Temperature Range		-40°C ~125°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE1: Valid provided that electrodes are kept at ambient temperature

ELECTRICAL CHARACTERISTICS

| Parameter	Symbol	Conditions		LLDB3	LLDB3TG	Unit
Break-over Voltage	V_{BO}	C= 22nF	Min.	28	30	V
			Typ.	32	32	
			Max.	36	34	
Break-over Voltage Symmetry	+/-V_{BO}	C= 22nF	Max.	+/-3	+/-2	V
Break-over Current	I_{BO}	C= 22nF	Max.	100	15	nA
Dynamic Breakover Voltage	ΔV	I_{BO} to I_F=10mA	Min.	5	9	V
Leakage Current	I_B	V_B= 0.5V_{BO} (MAX)	Max.	10		µA
Output Voltage	V_O	*see diagram 1	Min.	5		V

ELECTRICAL PARAMETER
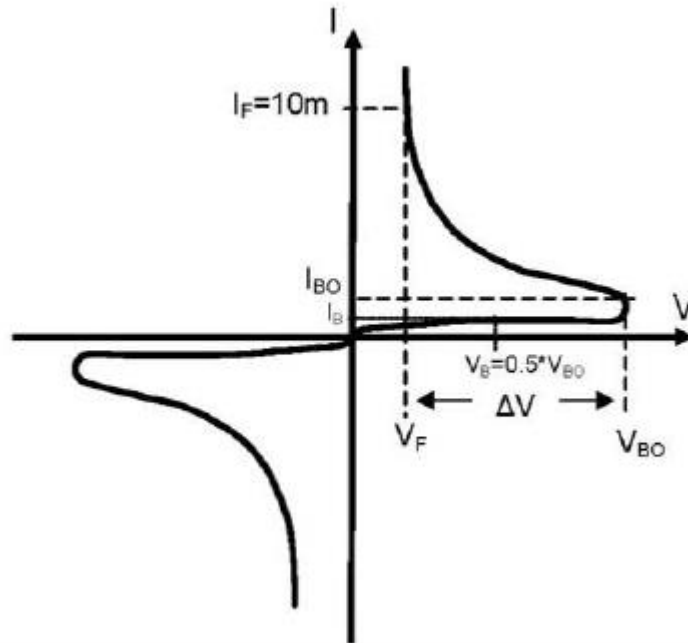
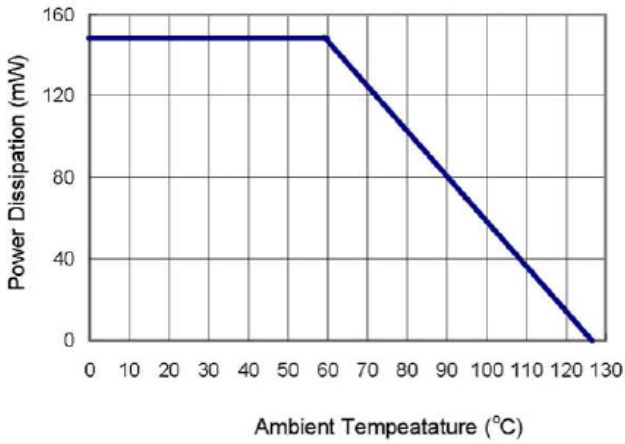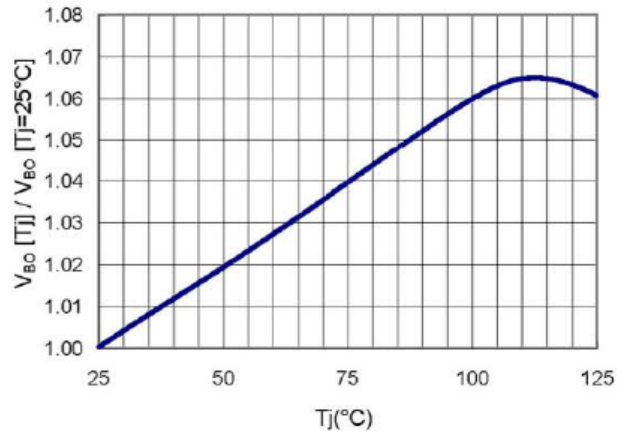| Symbol	Parameter
V_{BO}	Break-Over Voltage
I_{BO}	Break-Over Current
ΔV	Dynamic Breakover Voltage
I_B	Leakage Current at $V_B = 0.5 * V_{BO}$
V_F	Voltage at Current $I_F = 10mA$

TEST CIRCUIT
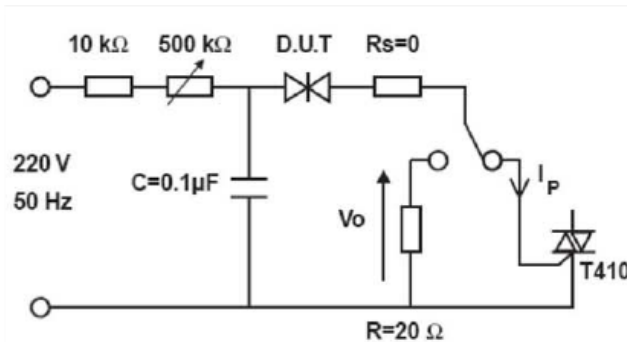
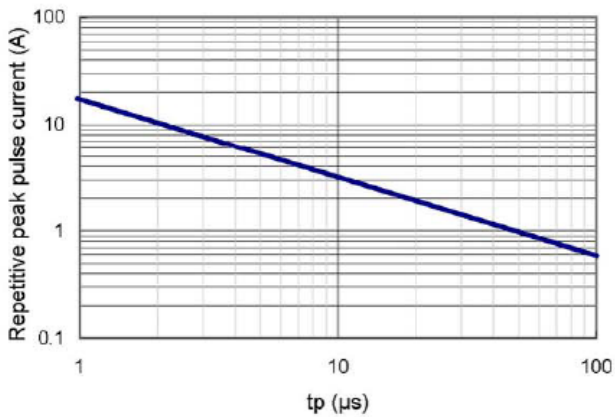## TYPICAL PERFORMANCE CHARACTERISTICS

1. Admissible Power Dissipation Curve

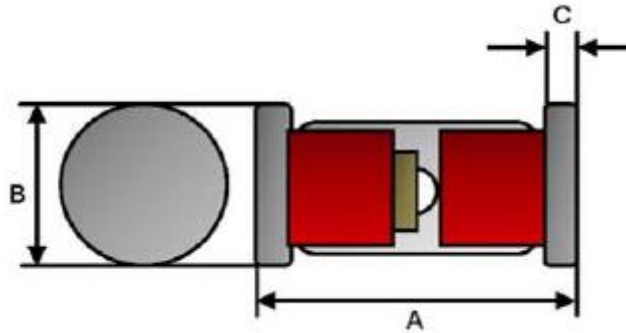2. Relative variation of V_{BO} vs. junction temperature (typical values)

3. Repetitive peak pulse current vs. pulse duration (maximum values)
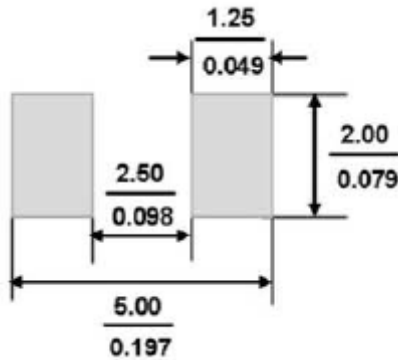
PACKAGE INFORMATION

Dimension in LL-34 (Unit: mm)

Suggested PDA Layout

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	3.300	3.700	0.130	0.146
B	1.400	1.600	0.055	0.063
C	0.200	0.500	0.008	0.020

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